

## Features

- Low-voltage and Standard-voltage Operation
  - 5.0 ( $V_{CC} = 4.5V$  to 5.5V)
  - 2.7 ( $V_{CC} = 2.7V$  to 5.5V)
- Internally Organized 4096 x 8, 8192 x 8
- 2-wire Serial Interface
- Schmitt Trigger, Filtered Inputs for Noise Suppression
- Bi-directional Data Transfer Protocol
- 100 kHz (2.7V) and 400 kHz (5V) Compatibility
- 32-byte Page Write Mode (Partial Page Writes Allowed)
- Self-timed Write Cycle (10 ms max)
- High Reliability
  - Endurance: 1 Million Write Cycles
  - Data Retention: 100 Years
  - ESD Protection: >3,000V

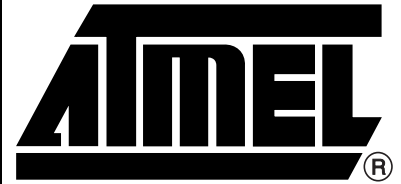
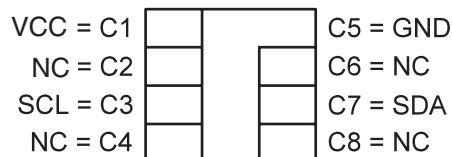
## Description

The AT24C32SC/64SC provides 32,768/65,536 bits of serial electrically erasable and programmable read only memory (EEPROM) organized as 4096/8192 words of 8 bits each. The devices are optimized for use in smart card applications where low-power and low-voltage operation may be essential. The devices are available in several standard ISO 7816 smart card modules (see Ordering Information). The entire family is available in both high-voltage (4.5V to 5.5V) and low-voltage (2.7V to 5.5V) versions. All devices are functionally equivalent to Atmel Serial EEPROM products offered in standard IC packages (PDIP, SOIC, EIAJ, LAP), with the exception of the slave address and Write Protect functions which are not required for smart card applications.

## Pin Configurations

Pad Name	Description	ISO Module Contact
VCC	Power Supply Voltage	C1
GND	Ground	C5
SCL	Serial Clock Input	C3
SDA	Serial Data Input/Output	C7
NC	No Connect	C2, C4, C6, C8

## Card Module Contact



## 2-wire Serial EEPROM Smart Card Modules

32K (4096 x 8)

64K (8192 x 8)

**AT24C32SC**  
**AT24C64SC**

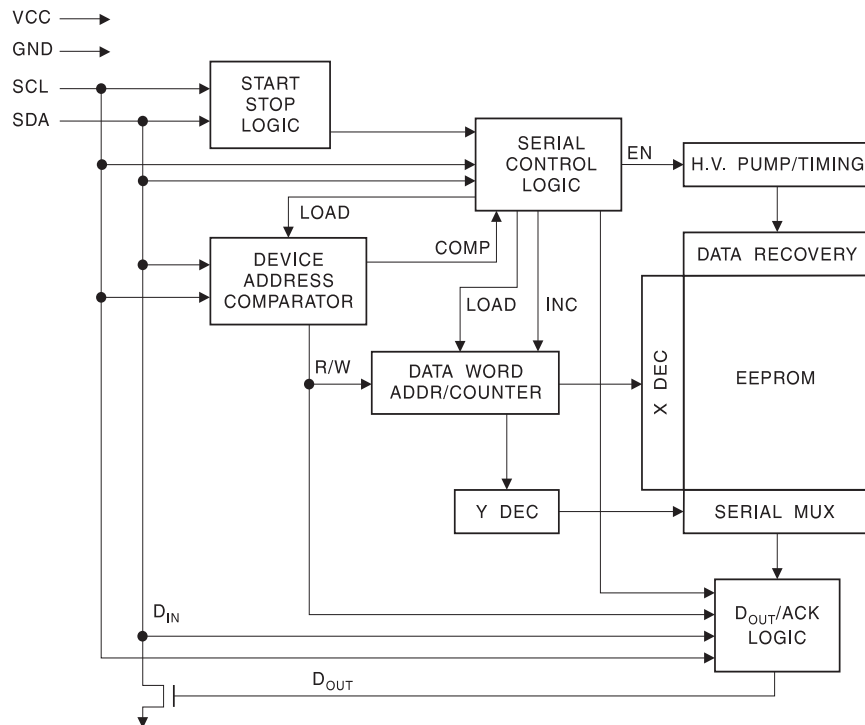


## Absolute Maximum Ratings\*

Operating Temperature.....	-55°C to +125°C
Storage Temperature.....	-65°C to +150°C
Voltage on Any Pin with Respect to Ground.....	-1.0V to +7.0V
Maximum Operating Voltage.....	6.25V
DC Output Current.....	5.0 mA

\*NOTICE: Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Block Diagram



## Pin Description

**SERIAL CLOCK (SCL):** The SCL input is used to positive edge clock data into each EEPROM device and negative edge clock data out of each device.

**SERIAL DATA (SDA):** The SDA pin is bidirectional for serial data transfer. This pin is open-drain driven and may be wire-ORed with any number of other open-drain or open-collector devices.

## Memory Organization

**AT24C32SC/64SC, 32K/64K SERIAL EEPROM:** The 32K/64K is internally organized as 128/256 pages of 32 bytes each. Random word addressing requires a 12/13 bit data word address.

## Pin Capacitance<sup>(1)</sup>

Applicable over recommended operating range from  $T_A = 25^\circ\text{C}$ ,  $f = 1.0\text{ MHz}$ ,  $V_{CC} = +2.7\text{V}$ .

Symbol	Test Condition	Max	Units	Conditions
$C_{I/O}$	Input/Output Capacitance (SDA)	8	pF	$V_{I/O} = 0\text{V}$
$C_{IN}$	Input Capacitance (SCL)	6	pF	$V_{IN} = 0\text{V}$

Note: 1. This parameter is characterized and is not 100% tested.

## DC Characteristics

Applicable over recommended operating range from:  $T_{AC} = 0^\circ\text{C}$  to  $+70^\circ\text{C}$ ,  $V_{CC} = +2.7\text{V}$  to  $+5.5\text{V}$  (unless otherwise noted).

Symbol	Parameter	Test Condition		Min	Typ	Max	Units
$V_{CC1}$	Supply Voltage			2.7		5.5	V
$V_{CC2}$	Supply Voltage			4.5		5.5	V
$I_{CC1}$	Supply Current	$V_{CC} = 5.0\text{V}$	Read at 100 kHz		0.4	1.0	mA
$I_{CC2}$	Supply Current	$V_{CC} = 5.0\text{V}$	Write at 100 kHz		2.0	3.0	mA
$I_{SB1}$	Standby Current (2.7V option)	$V_{CC} = 2.7\text{V}$	$V_{IN} = V_{CC}$ or GND			0.5	$\mu\text{A}$
		$V_{CC} = 5.5\text{V}$				2.0	
$I_{SB2}$	Standby Current (5V option)	$V_{CC} = 4.5 - 5.5\text{V}$	$V_{IN} = V_{CC}$ or GND			2.0	$\mu\text{A}$
$I_{LI}$	Input Leakage Current	$V_{IN} = V_{CC}$ or GND			0.10	3.0	$\mu\text{A}$
$I_{LO}$	Output Leakage Current	$V_{OUT} = V_{CC}$ or GND			0.05	3.0	$\mu\text{A}$
$V_{IL}$	Input Low Level <sup>(1)</sup>			-0.6		$V_{CC} \times 0.3$	V
$V_{IH}$	Input High Level <sup>(1)</sup>			$V_{CC} \times 0.7$		$V_{CC} + 0.5$	V
$V_{OL}$	Output Low Level <sup>(1)</sup>	$V_{CC} = 3.0\text{V}$	$I_{OL} = 2.1\text{mA}$			0.4	V

Note: 1.  $V_{IL}$  min and  $V_{IH}$  max are reference only and are not tested.

## AC Characteristics

Applicable over recommended operating range from  $T_A = 0^\circ\text{C}$  to  $+70^\circ\text{C}$ ,  $V_{CC} = +2.7\text{V}$  to  $+5.5\text{V}$ ,  $CL = 1$  TTL Gate and  $100\text{ pF}$  (unless otherwise noted).

Symbol	Parameter	2.7-volt		5.0-volt		Units
		Min	Max	Min	Max	
$f_{SCL}$	Clock Frequency, SCL		100		400	kHz
$t_{LOW}$	Clock Pulse Width Low	4.7		1.2		$\mu\text{s}$
$t_{HIGH}$	Clock Pulse Width High	4.0		0.6		$\mu\text{s}$
$t_I$	Noise Suppression Time <sup>(1)</sup>		100		50	ns
$t_{AA}$	Clock Low to Data Out Valid	0.1	4.5	0.1	0.9	$\mu\text{s}$
$t_{BUF}$	Time the bus must be free before a new transmission can start <sup>(1)</sup>	4.7		1.2		$\mu\text{s}$
$t_{HD,STA}$	Start Hold Time	4.0		0.6		$\mu\text{s}$
$t_{SU,STA}$	Start Set-up Time	4.7		0.6		$\mu\text{s}$
$t_{HD,DAT}$	Data In Hold Time	0		0		$\mu\text{s}$
$t_{SU,DAT}$	Data In Set-up Time	200		100		ns
$t_R$	Inputs Rise Time <sup>(1)</sup>		1.0		0.3	$\mu\text{s}$
$t_F$	Inputs Fall Time <sup>(1)</sup>		300		300	ns
$t_{SU,STO}$	Stop Set-up Time	4.7		0.6		$\mu\text{s}$
$t_{DH}$	Data Out Hold Time	100		50		ns
$t_{WR}$	Write Cycle Time		10		10	ms
Endurance <sup>(1)</sup>	5.0V, $25^\circ\text{C}$ , Page Mode	1M		1M		Write Cycles

Note: 1. This parameter is characterized and is not 100% tested.

## Device Operation

**CLOCK and DATA TRANSITIONS:** The SDA pin is normally pulled high with an external device. Data on the SDA pin may change only during SCL low time periods (refer to Data Validity timing diagram). Data changes during SCL high periods will indicate a start or stop condition as defined below.

**START CONDITION:** A high-to-low transition of SDA with SCL high is a start condition which must precede any other command (refer to Start and Stop Definition timing diagram).

**STOP CONDITION:** A low-to-high transition of SDA with SCL high is a stop condition. After a read sequence, the stop command will place the EEPROM in a standby power mode (refer to Start and Stop Definition timing diagram).

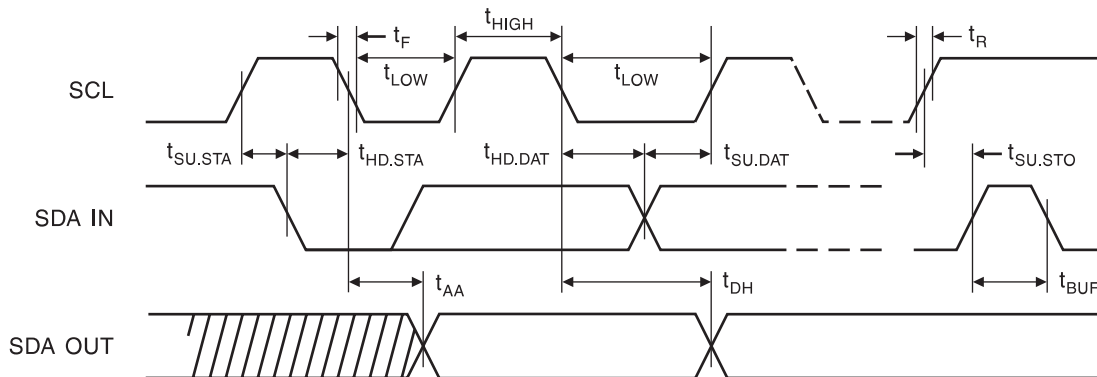
**ACKNOWLEDGE:** All addresses and data words are serially transmitted to and from the EEPROM in 8-bit words. The EEPROM sends a zero during the ninth clock cycle to acknowledge that it has received each word.

**STANDBY MODE:** The AT24C32SC/64SC features a low power standby mode which is enabled: a) upon power-up and b) after the receipt of the STOP bit and the completion of any internal operations.

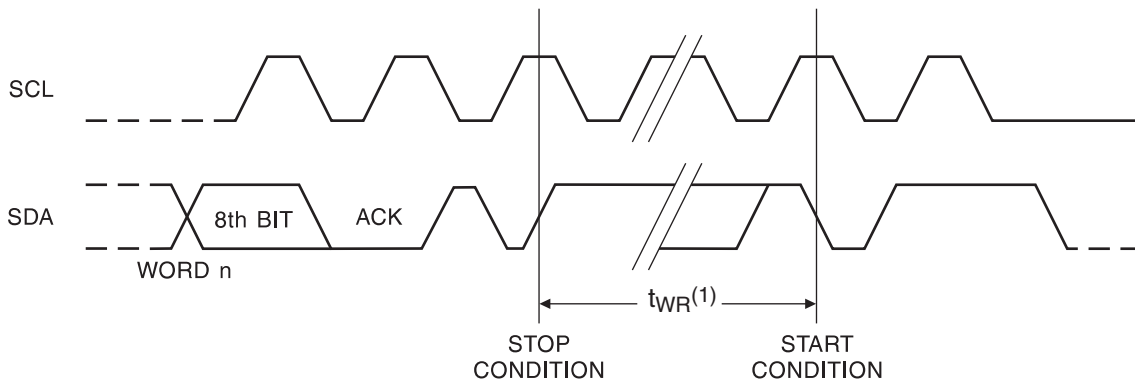
**MEMORY RESET:** After an interruption in protocol, power loss or system reset, any 2-wire part can be reset by following these steps:

1. Clock up to 9 cycles.
2. Look for SDA high in each cycle while SCL is high.
3. Create a start condition as SDA is high.

**Bus Timing**  
**SCL: Serial Clock, SDA: Serial Data I/O**

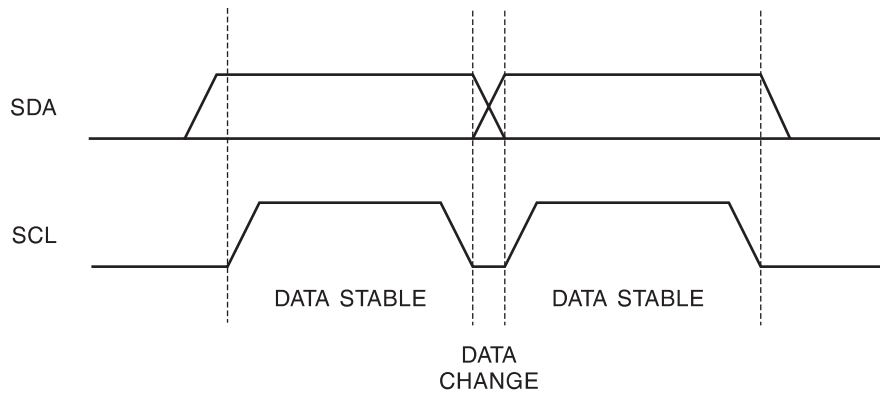


**Write Cycle Timing**  
**SCL: Serial Clock, SDA: Serial Data I/O**

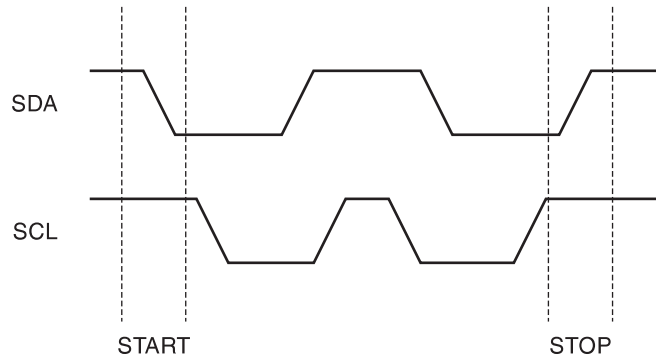


Note: 1. The write cycle time  $t_{WR}$  is the time from a valid stop condition of a write sequence to the end of the internal clear/write cycle.

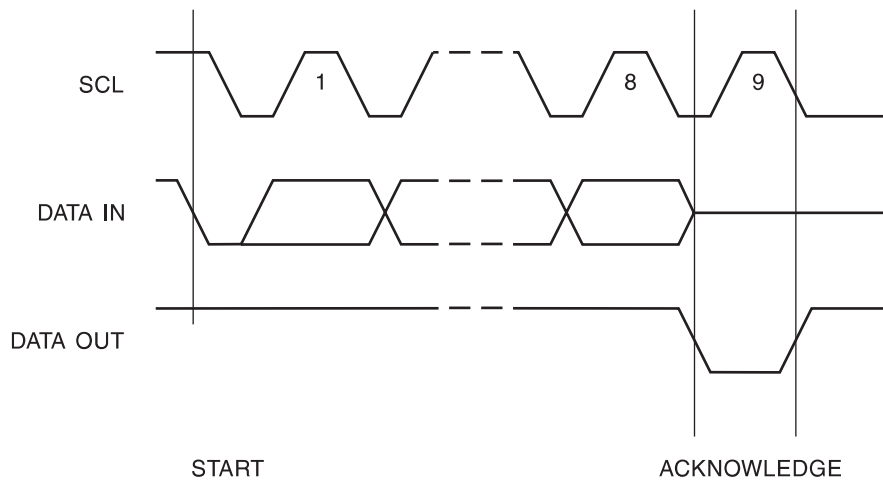
## Data Validity



## Start and Stop Definition



## Output Acknowledge



## Device Addressing

The 32K/64K EEPROM requires an 8-bit device address word following a start condition to enable the chip for a read or write operation (refer to Figure 1). The device address word consists of a mandatory one, zero sequence for the first four most significant bits as shown. This is common to all 2-wire EEPROM devices.

The next three bits of the device address word are unused. These three unused bits should be set to “0”.

The eighth bit of the device address is the read/write operation select bit. A read operation is initiated if this bit is high and a write operation is initiated if this bit is low.

Upon a compare of the device address, the EEPROM will output a zero. If a compare is not made, the device will return to standby state.

## Write Operations

**BYTE WRITE:** A write operation requires two 8-bit data word addresses following the device address word and acknowledgment. Upon receipt of this address, the EEPROM will again respond with a zero and then clock in the first 8-bit data word. Following receipt of the 8-bit data word, the EEPROM will output a zero and the addressing device, such as a microcontroller, must terminate the write sequence with a stop condition. At this time the EEPROM enters an internally-timed write cycle,  $t_{WR}$ , to the nonvolatile memory. All inputs are disabled during this write cycle and the EEPROM will not respond until the write is complete (refer to Figure 2).

**PAGE WRITE:** The 32K/64K EEPROM is capable of 32-byte page writes.

A page write is initiated the same way as a byte write, but the microcontroller does not send a stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges receipt of the first data word, the microcontroller can transmit up to 31 more data words. The EEPROM will respond with a zero after each data word received. The microcontroller must terminate the page write sequence with a stop condition (refer to Figure 3).

The data word address lower five bits are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location. When the word address, internally generated, reaches the page boundary, the following byte is placed at the beginning of the same page. If more than 32 data words are transmitted to the EEPROM, the data word address will “roll over” and previous data will be overwritten.

**ACKNOWLEDGE POLLING:** Once the internally-timed write cycle has started and the EEPROM inputs are disabled, acknowledge polling can be initiated. This involves sending a start condition followed by the device address word. The read/write bit is representative of the operation desired. Only if the internal write cycle has completed will the EEPROM respond with a zero, allowing the read or write sequence to continue.

## Read Operations

Read operations are initiated the same way as write operations with the exception that the read/write select bit in the device address word is set to one. There are three read operations: current address read, random address read and sequential read.

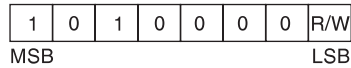
**CURRENT ADDRESS READ:** The internal data word address counter maintains the last address accessed during the last read or write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address “roll over” during read is from the last byte of the last memory page, to the first byte of the first page. The address “roll over” during write is from the last byte of the current page to the first byte of the same page.

Once the device address with the read/write select bit set to one is clocked in and acknowledged by the EEPROM, the current address data word is serially clocked out. The microcontroller does not respond with an input zero but does generate a following stop condition (refer to Figure 4).

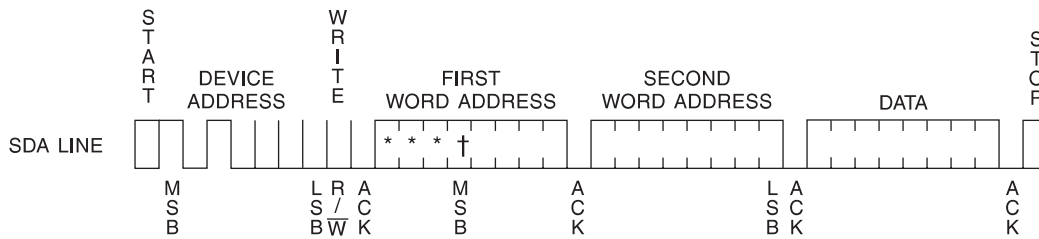
**RANDOM READ:** A random read requires a “dummy” byte write sequence to load in the data word address. Once the device address word and data word address are clocked in and acknowledged by the EEPROM, the microcontroller must generate another start condition. The microcontroller now initiates a current address read by sending a device address with the read/write select bit high. The EEPROM acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a zero but does generate a following stop condition (refer to Figure 5).

**SEQUENTIAL READ:** Sequential reads are initiated by either a current address read or a random address read. After the microcontroller receives a data word, it responds with an acknowledge. As long as the EEPROM receives an acknowledge, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will “roll over” and the sequential read will continue. The sequential read operation is terminated when the microcontroller does not respond with a zero but does generate a following stop condition (refer to Figure 6).

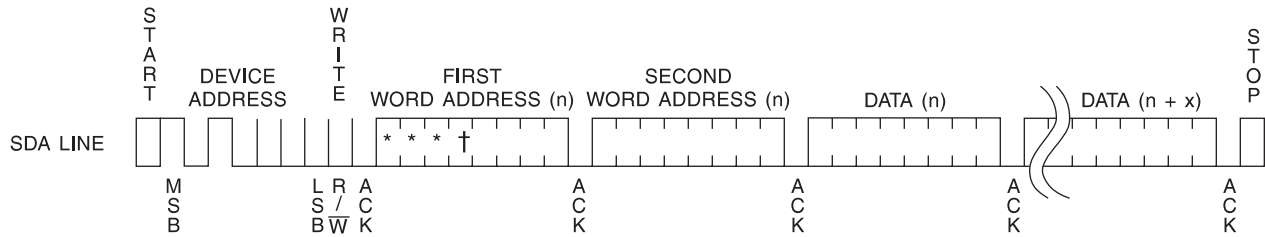
**Figure 1. Device Address**



**Figure 2. Byte Write**



**Figure 3. Page Write**



- Notes:
1. \* = DON'T CARE bits
  2. † = DON'T CARE bits for the 32K



Figure 4. Current Address Read

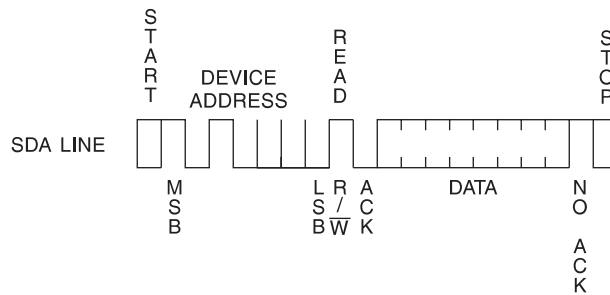
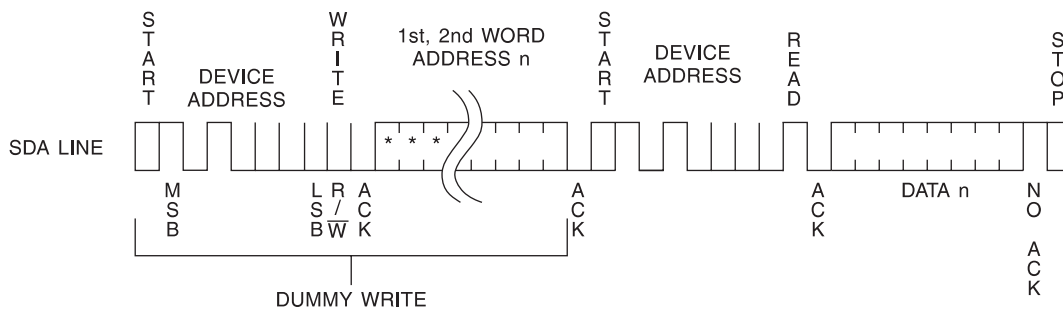
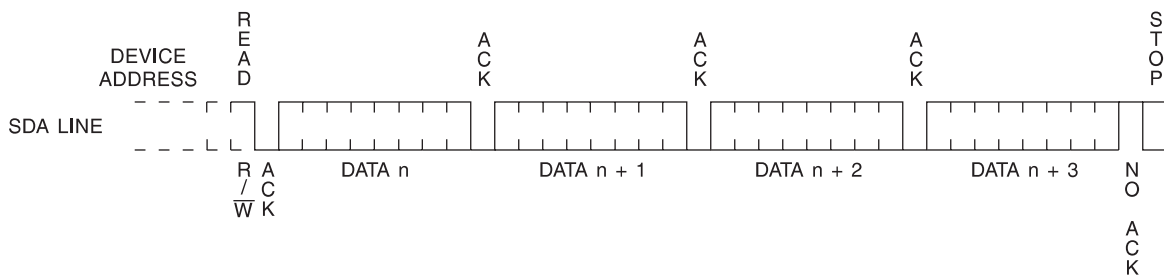


Figure 5. Random Read



Note: 1. \* = DON'T CARE bits

Figure 6. Sequential Read





## AT24C32SC Ordering Information

Ordering Code	Package <sup>(1)</sup>	Voltage Range	Temperature Range
AT24C32SC - 09AT - 2.7 AT24C32SC - 09BT - 2.7 AT24C32SC - 09CT - 2.7 AT24C32SC - 09DT - 2.7	M2 - A Module M2 - B Module M4 - C Module M4 - D Module	2.7V to 5.5V	Commercial (0°C to 70°C)
AT24C32SC - 09AT AT24C32SC - 09BT AT24C32SC - 09CT AT24C32SC - 09DT	M2 - A Module M2 - B Module M4 - C Module M4 - D Module	4.5V to 5.5V	Commercial (0°C to 70°C)

## AT24C64SC Ordering Information

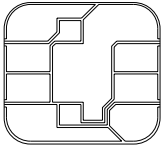
Ordering Code	Package <sup>(1)</sup>	Voltage Range	Temperature Range
AT24C64SC - 09AT - 2.7 AT24C64SC - 09BT - 2.7 AT24C64SC - 09CT - 2.7 AT24C64SC - 09DT - 2.7	M2 - A Module M2 - B Module M4 - C Module M4 - D Module	2.7V to 5.5V	Commercial (0°C to 70°C)
AT24C64SC - 09AT AT24C64SC - 09BT AT24C64SC - 09CT AT24C64SC - 09DT	M2 - A Module M2 - B Module M4 - C Module M4 - D Module	4.5V to 5.5V	Commercial (0°C to 70°C)

Package Type <sup>(1)</sup>	
<b>M2 - A Module</b>	M2 ISO 7816 Smart Card Module
<b>M2 - B Module</b>	M2 ISO 7816 Smart Card Module with Atmel Logo
<b>M4 - C Module</b>	M4 ISO 7816 Smart Card Module
<b>M4 - D Module</b>	M4 ISO 7816 Smart Card Module with Atmel Logo

Note: 1. Formal drawings may be obtained from an Atmel Sales Office.

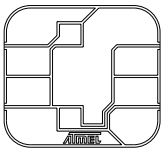
## Smart Card Modules

### M2 - A Module - Ordering Code: 09AT



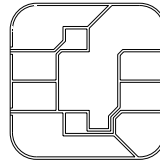
Module Size: M2  
 Dimension<sup>(1)</sup>: 12.6 x 11.4 mm  
 Glob Top: Square: 8.6 x 8.6 mm  
 Thickness: 0.58 mm max.  
 Pitch: 14.25 mm

### M2 - B Module - Ordering Code: 09BT



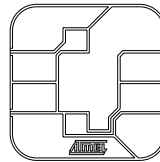
Module Size: M2  
 Dimension<sup>(1)</sup>: 12.6 x 11.4 mm  
 Glob Top: Square: 8.6 x 8.6 mm  
 Thickness: 0.58 mm max.  
 Pitch: 14.25 mm

### M4 - C Module - Ordering Code: 09CT



Module Size: M4  
 Dimension<sup>(1)</sup>: 12.6 x 12.6 mm  
 Glob Top: Square: 8.6 x 8.6 mm  
 Thickness: 0.58 mm  
 Pitch: 14.25 mm

### M4 - D Module - Ordering Code: 09DT



Module Size: M4  
 Dimension<sup>(1)</sup>: 12.6 x 12.6 mm  
 Glob Top: Square: 8.6 x 8.6 mm  
 Thickness: 0.58 mm max.  
 Pitch: 14.25 mm

Note: 1. The module dimensions listed refer to the dimensions of the exposed metal contact area. The actual dimensions of the module after excise or punching from the carrier tape are generally 0.4 mm greater in both directions (i.e. a punched M2 module will yield 13.0 x 11.8 mm).



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